

Medium Power Silicon Rectifier Diodes, 12 A



DO-203AA (DO-4)

FEATURES

- Voltage ratings from 50 to 1000 V
- High surge capability
- Low thermal impedance
- High temperature rating
- Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- RoHS compliant



PRODUCT SUMMARY

$I_{F(AV)}$	12 A
-------------	------

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		12 ⁽¹⁾	A
	T_C	150 ⁽¹⁾	°C
I_{FSM}	50 Hz	230	A
	60 Hz	240 ⁽¹⁾	
I^2t	50 Hz	260	A ² s
	60 Hz	240	
T_C		- 65 to 200	°C
V_{RRM}	Range	50 to 1000 ⁽¹⁾	V

Note

⁽¹⁾ JEDEC registered values

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER ⁽²⁾	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	$V_{R(RMS)}$, MAXIMUM RMS REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE V
	$T_C = - 65\text{ °C TO } 200\text{ °C}$	$T_C = - 65\text{ °C TO } 200\text{ °C}$	$T_C = - 65\text{ °C TO } 200\text{ °C}$	$T_C = - 65\text{ °C TO } 200\text{ °C}$
1N1199A	50 ⁽¹⁾	35 ⁽¹⁾	100 ⁽¹⁾	50 ⁽¹⁾
1N1200A	100 ⁽¹⁾	70 ⁽¹⁾	200 ⁽¹⁾	100 ⁽¹⁾
1N1201A	150 ⁽¹⁾	105 ⁽¹⁾	300 ⁽¹⁾	150 ⁽¹⁾
1N1202A	200 ⁽¹⁾	140 ⁽¹⁾	350 ⁽¹⁾	200 ⁽¹⁾
1N1203A	300 ⁽¹⁾	210 ⁽¹⁾	450 ⁽¹⁾	300 ⁽¹⁾
1N1204A	400 ⁽¹⁾	280 ⁽¹⁾	600 ⁽¹⁾	400 ⁽¹⁾
1N1205A	500 ⁽¹⁾	350 ⁽¹⁾	700 ⁽¹⁾	500 ⁽¹⁾
1N1206A	600 ⁽¹⁾	420 ⁽¹⁾	800 ⁽¹⁾	600 ⁽¹⁾
1N3670A	700 ⁽¹⁾	490	900 ⁽¹⁾	700 ⁽¹⁾
1N3671A	800 ⁽¹⁾	560	1000 ⁽¹⁾	800 ⁽¹⁾
1N3672A	900 ⁽¹⁾	630	1100 ⁽¹⁾	900 ⁽¹⁾
1N3673A	1000 ⁽¹⁾	700	1200 ⁽¹⁾	1000 ⁽¹⁾

Notes

⁽¹⁾ JEDEC registered values

⁽²⁾ Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

1N1...A, 1N36..A Series



Vishay High Power Products

Medium Power
Silicon Rectifier Diodes, 12 A

FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° sinusoidal conduction		12 ⁽¹⁾	A
				150 ⁽¹⁾	°C
Maximum peak one cycle non-repetitive surge current	I_{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V_{RRM} applied	230	A
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		240 ⁽¹⁾	
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with V_{RRM} applied following surge = 0	275	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		285	
Maximum I^2t for fusing	I^2t	t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = 200$ °C	260	A ² s
		t = 8.3 ms		240	
Maximum I^2t for individual device fusing	I^2t	t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = 200$ °C	370	
		t = 8.3 ms		340	
Maximum $I^2\sqrt{t}$ for individual device fusing	$I^2\sqrt{t}$ ⁽²⁾	t = 0.1 to 10 ms, $V_{RRM} = 0$ following surge		3715	A ² √s
Maximum forward voltage drop	V_{FM}	$I_{F(AV)} = 12$ A (38 A peak), $T_C = 25$ °C		1.35 ⁽¹⁾	V
Maximum average reverse current	$I_{R(AV)}$ ⁽³⁾	Maximum rated $I_{F(AV)}$ and T_C		$V_{RRM} = 50$	3.0 ⁽¹⁾
				$V_{RRM} = 100$	2.5 ⁽¹⁾
				$V_{RRM} = 150$	2.25 ⁽¹⁾
				$V_{RRM} = 200$	2.0 ⁽¹⁾
				$V_{RRM} = 300$	1.75 ⁽¹⁾
				$V_{RRM} = 400$	1.5 ⁽¹⁾
				$V_{RRM} = 500$	1.25 ⁽¹⁾
				$V_{RRM} = 600$	1.0 ⁽¹⁾
				$V_{RRM} = 700$	0.9 ⁽¹⁾
				$V_{RRM} = 800$	0.8 ⁽¹⁾
				$V_{RRM} = 900$	0.7 ⁽¹⁾
				$V_{RRM} = 1000$	0.6 ⁽¹⁾

Notes

⁽¹⁾ JEDEC registered values

⁽²⁾ I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

⁽³⁾ Maximum peak reverse current (I_{RM}) under same conditions $\approx 2 \times$ rated $I_{R(AV)}$



THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum operating case and storage temperature range	T_C, T_{Stg}		- 65 to 200 ⁽¹⁾	°C
Maximum internal thermal resistance, junction to case	R_{thJC}	DC operation	2.0 ⁽¹⁾	°C/W
Thermal resistance, case to sink	R_{thCS}	Mounting surface, smooth, flat and greased	0.5	
Mounting torque	minimum	Torque applied to nut; non-lubricated threads	1.36 (12)	N · m (lbf · in)
	maximum		1.69 (15)	
	minimum	Torque applied to nut; lubricated threads	1.07 (9.45)	
	maximum		1.30 (11.55)	
	minimum	Torque applied to device case; lubricated threads	1.17 (10.35)	
	maximum		1.43 (12.65)	
Approximate weight			7.0	g
			0.25	oz.
Case style		JEDEC	DO-203AA (DO-4)	

Note

⁽¹⁾ JEDEC registered values

1N1...A, 1N36..A Series

Vishay High Power Products

Medium Power
Silicon Rectifier Diodes, 12 A



Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature



Fig. 4 - Maximum Forward Voltage vs. Forward Current



Fig. 2 - Maximum Low Level Forward Power Loss vs. Average Forward Current



Fig. 5 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration

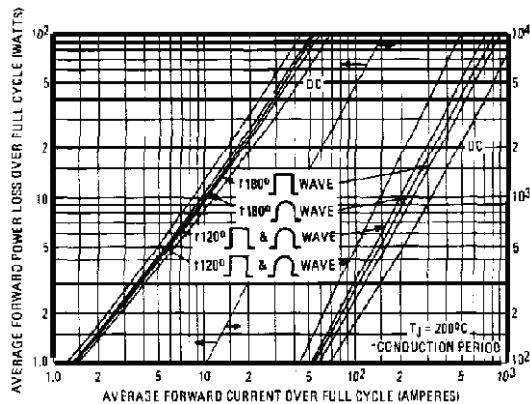


Fig. 3 - Maximum High Level Forward Power Loss vs. Average Forward Current

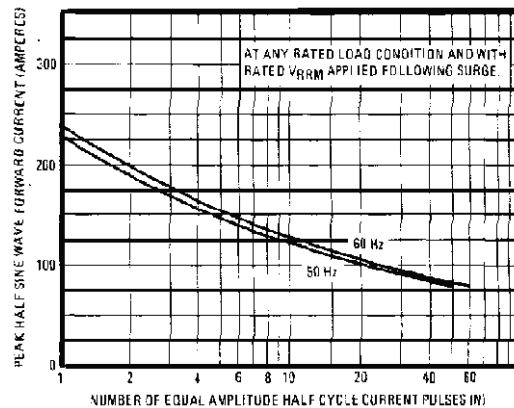


Fig. 6 - Maximum Non-Repetitive 50 Hz Surge Current vs. Number of Current Pulses

LINKS TO RELATED DOCUMENTS

Dimensions

<http://www.vishay.com/doc?95311>



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.